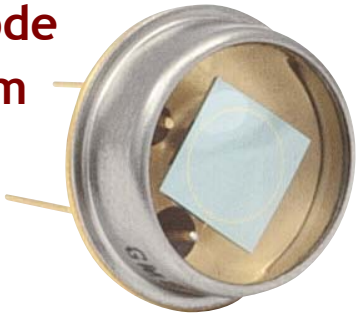
Ge Photodiode 800-1800 nm

FDG50



Description

The Thorlabs FDG50, germanium (Ge) photodiode is ideal for measuring both pulsed and CW fiber light with sensitivity from 800 to 1800 nm. The detector is housed in a TO-8 package for ease of use and integration into exiting system. Under reverse bias application, the photodiode anode produces a current, which is a function of the incident light power and the wavelength. The responsivity $\Re(\lambda)$, can be read from Figure 1 to estimate the amount of photocurrent per incident light energy. The photodiode current can be converted to a voltage by placing a load resistor (R_L) between the photodiode anode and the circuit ground. The output voltage is derived as:

$$V_o = P \times \Re \times R_L$$

The bandwidth, f_{BW}, and the rise time response, t_R, are determined from the diode capacitance, C_J, and the load resistance, R_L, as shown below. The diode capacitance can be lowered by placing a bias voltage from the photodiode cathode to the circuit ground.

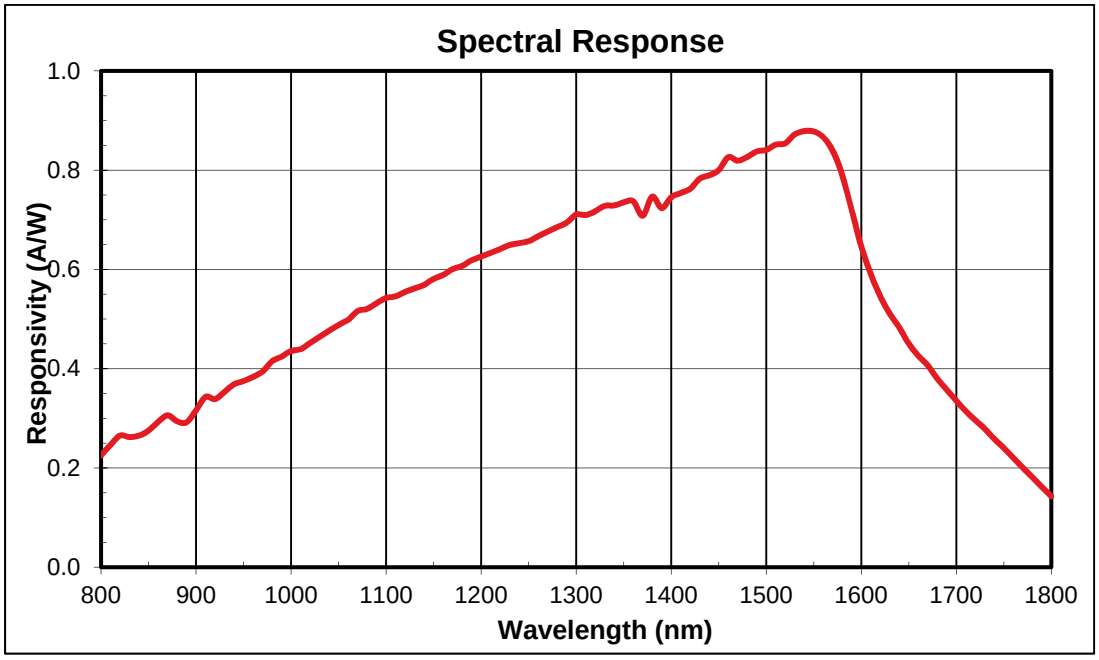
$$f_{BW} = \frac{1}{(2\pi)R_L C_J},\ t_R = \frac{0.35}{f_{BW}}$$

Specifications

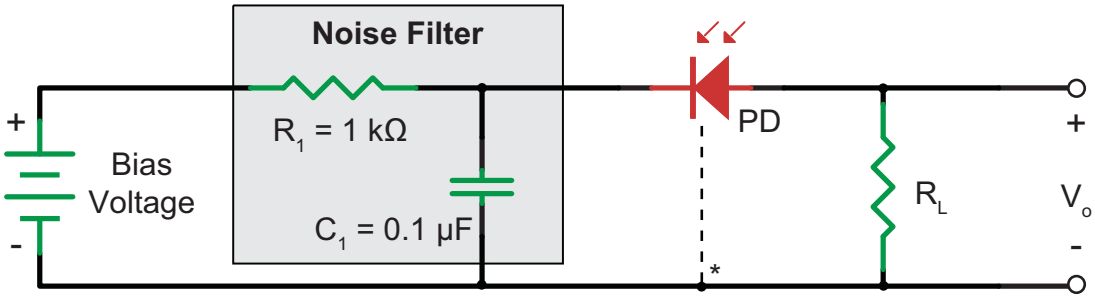
Specification		Value
Wavelength Range	λ	800 - 1800 nm
Peak Wavelength	λ_p	1550 nm (Typ.)
Responsivity	$\Re(\lambda_p)$	0.85 A/W (Typ.)
Active Area Diameter		5.0 mm
Rise/Fall Time (R_L=50 Ω, 10 V)	t_r/t_f	220 ns (Typ.)
NEP (1550 nm)	W/√Hz	4.0 x 10^{-12} (Typ.)
Dark Current (5 V)	I_d	60 µA (Max.)
Capacitance (10 V) **Capacitance (0 V)**	C_j	1800 pF (Max.) 16000 pF (Max.)
Shunt Resistance	R_{Shunt}	4000 Ω (Typ.)
Package		TO-8
Sensor Material		Germanium (Ge)

Maximum Rating	
Max Bias (Reverse) Voltage	10 V
Operating Temperature	-55 to 60 °C
Storage Temperature	-55 to 60 °C

Typical Spectral Intensity Distribution

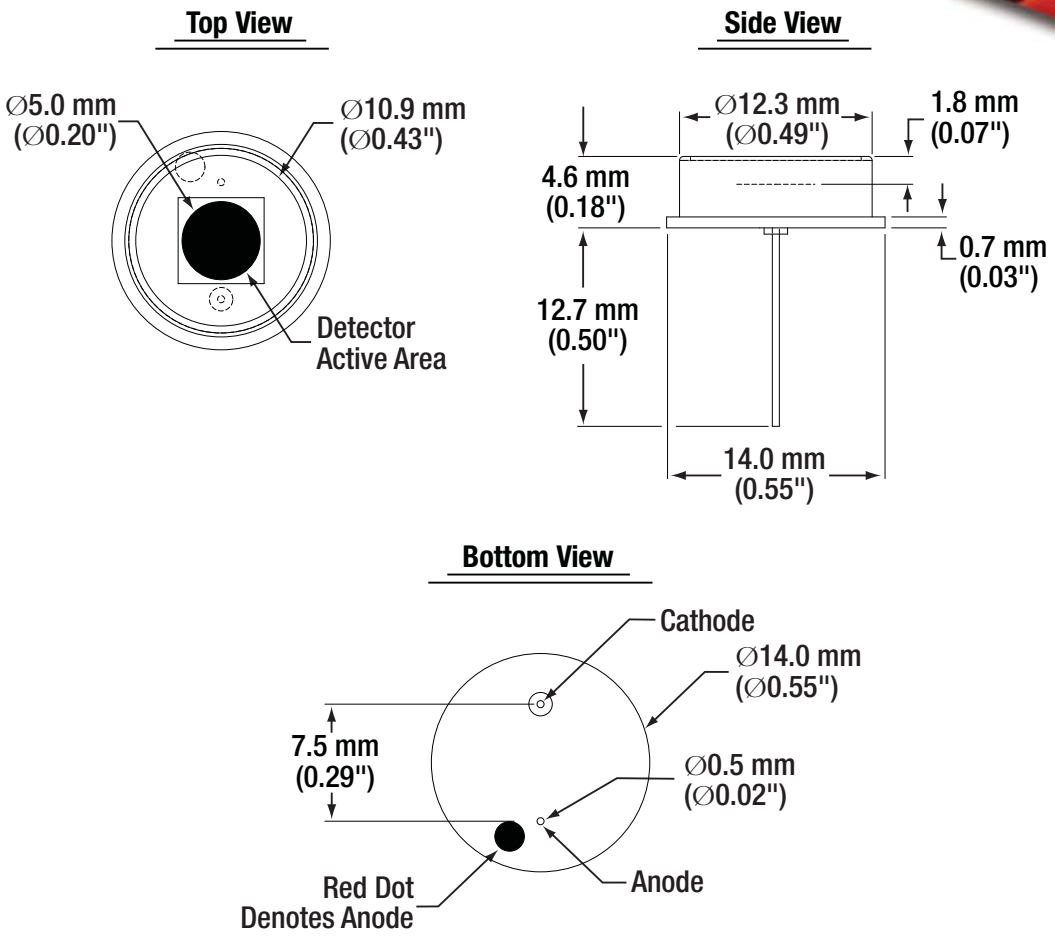


Recommended Circuit



* Case ground for PD with a third lead.

Drawing



Precautions and Warranty Information

These products are ESD (electro static discharge) sensitive and as a result are not covered under warranty. In order to ensure the proper functioning of a photodiode care must be given to maintain the highest standards of compliance to the maximum electrical specifications when handling such devices. The photodiodes are particularly sensitive to any value that exceeds the absolute maximum ratings of the product. Any applied voltage in excess of the maximum specification will cause damage and possible complete failure to the product. The user must use handling procedures that prevent any electro static discharges or other voltage surges when handling or using these devices.

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2. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system or to affect its safety or effectiveness.
3. The Thorlabs products described in this document are not intended nor warranted for usage in Military Applications.